

PATTERNING OF SELF-ASSEMBLED MONOLAYERS (SAMS)

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Abstract

Self-assembled monolayers (SAMs) has recently received much attention because of their wide range in applications such as layers in biosensors, electronic active layers or interlayers in organic electronic devices like organic light emitting diodes (OLEDs), organic photovoltaics (OPVs), organic thin film transistors (OTFTs). Photolithography is a basic and long established technique used in the preparation of processors and other electronic components. This paper deals with patterning of self-assembled monolayers prepared on gold and silver layers using photolithography. Firstly, the prepared self-assembled monolayers were characterized by scanning electron microscopy (SEM), atomic force microscopy (AFM) and Fourier-transform infrared spectroscopy (FTIR). Subsequently testing patterns according to the resolution chart test were exposed by UV lithography. These prepared patterns were characterized by optical microscopy, atomic force microscopy (AFM) and scanning electron microscopy (SEM).

Keywords: Self-assembled monolayers, photolithography, SEM, AFM, FTIR, magnetron sputtering

1. INTRODUCTION

The self-assembled monolayers (SAMs), which were discovered about 30 years ago, currently offer a wide range of applications in micro and nanoelectronics, printed electronics on flexible substrates, various types of sensors, biosensors and, above all, active intermediate layers for organic light emitting diodes (OLEDs) and organic photovoltaics (OPVs) [1]. Thus, spontaneously formed monolayers can provide the necessary monolayer properties in the preparation of various functional structures. Alkanethiols are often used for the preparation of the layers [2,3], when the molecules of material are organized on the metal surface (predominantly noble metals such as gold or silver) in a crystalline or semi-crystalline structure [4,5]. Various structures with defined use can be created on the resulting layer. One of the suitable, reliable and well-established methods useful for this purpose is UV photolithography [6]. SAMs (**Figure 1**) will form a resist-like surface on a suitable metal layer, and since alkanethiols are UV-sensitive, the prepared layer serves as a resist through which it is possible to treat and form functional structures on the metal surface below the self-organized layer.



Figure 1 Self assembled monolayer

2. PREPARATION OF MONOLAYERS

1-octadecanthiol (ODT, Sigma Aldrich, 98%) from the group of alkanethiols was used for prepare of selfassembled monolayers. The monolayers grew on silicon substrates coated with gold or silver. The metal layers



on silicon were sputtered by magnetron sputtering, the thickness of gold layer for the preparation of ODT layers was 20 nm, and the thickness of silver layer was 15 nm. 10 mM solution of ODT in isopropanol was used for layer growth. The organization of molecules took 6 hours and the final layers were baked at 50 °C for 12 hours.

3. CHARACTERIZATION METHODS

FTIR spectra of thin layers were investigated by FTIR spectrometer S6700 from Nicolet - ThermoScientific (**Figure 2**). The presence of asymmetric mode CH_2 at 2917.51 cm⁻¹, symmetric mode CH_2 at 2848.16 cm⁻¹ and CH_3 stretching mode at 2958.60 cm⁻¹ indicates well organized monolayer.



Figure 2 FTIR spectra of prepared monolayer of 1-Octadecanthiol (CH3(CH2)17-SH)

Characterization of prepared monolayers was done by scanning electron microscope Nova NanoSEM 450 (FEI) with Schottky field emission electron source operated at acceleration voltage 5 kV. The images of the prepared layers show that the layer prepared on the silver surface shows bigger defects than the layer prepared on gold (**Figure 3**).



Figure 3 SEM images of prepared ODT monolayer left) silver substrate, right) gold substrate

The AFM images can be seen, the images of the prepared monolayers were taken by atomic force microscope Dimension ICON (**Figure 4**).





Figure 4 AFM images of prepared ODT monolayer left) silver substrate, right) gold substrate (scan size 100 x 100 nm)

4. UV PHOTOLITHOGRAPHY AND RESULTS

Testing pattern was designed according to the USAF 1951 resolution test chart extended by star pattern (**Figure 5**). The exposure was carried out by Phillips mercury UV lamp 400 W for 20 minutes because of needs to achieve proper oxidation of layer. The development process was done by wet way in isopropanol for 30 seconds. The temperature of developer was at room temperature - 22.5 °C. Then the samples were rinsed in isopropanol and deionized water.



Figure 5 Exposure test design



Figure 6 Testing element 1-1 from USAF 1951 test (left) and part of star motif (right)



After development the structures were observed by optical microscopy Leica DVM 2500 (**Figure 6**). The dimension of line was determined in the element 1-1 of USAF test. The determined width of line is 298 μ m compared to the designed width of 250 μ m.

The exposed and developed structures were also observed by scanning electron microscope (Figure 7).



Figure 7 Testing element 0-4 from USAF 1951 test (left) and part of star motif (right).

The measured width of lines was 360 μ m respectively 385 μ m in comparison with designed width of 353.55 μ m.

The exposed pattern was measured by atomic force microscopy (**Figure 8**). There is visible difference between exposed and non-exposed area but no sharp border.



Figure 8 AFM image of border between exposed and non-exposed areas.

5. CONCLUSION

We successfully patterned self-assembled monolayer organized from 1-octadecanthiol. The self-assembled monolayers were prepared on silver and gold surface. The prepared monolayers were characterized by scanning electron microscopy, atomic force microscopy and Fourier-transform infrared spectroscopy. ODT



monolayers were patterned by UV lithography and exposed patterns were observed and evaluated by optical microscopy, atomic force microscopy and scanning electron microscopy, the linewidths of exposed structures were determined from the measurements.

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